SCES561D-MARCH 2004-REVISED APRIL 2008

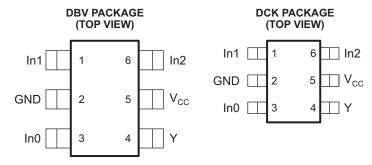


# **CONFIGURABLE MULTIPLE-FUNCTION GATE**

#### **FEATURES**

- Qualified for Automotive Applications
- Supports 5-V V<sub>CC</sub> Operation
- Inputs Accept Voltages to 5.5 V
- Max t<sub>nd</sub> of 7.3 ns at 3.3 V
- Low Power Consumption, 10-μA Max I<sub>CC</sub>
- ±24-mA Output Drive at 3.3 V
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation

- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)
- Choose From Nine Specific Logic Functions



See mechanical drawings for dimensions.

# **DESCRIPTION/ORDERING INFORMATION**

This configurable multiple-function gate is designed for 1.65-V to 5.5-V V<sub>CC</sub> operation.

The SN74LVC1G97 features configurable multiple functions. The output state is determined by eight patterns of 3-bit input. The user can choose the logic functions MUX, AND, OR, NAND, NOR, inverter, and noninverter. All inputs can be connected to  $V_{CC}$  or GND.

This device functions as an independent gate but, because of Schmitt action, it may have different input threshold levels for positive-going  $(V_{T_{+}})$  and negative-going  $(V_{T_{-}})$  signals.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

# ORDERING INFORMATION(1)

T <sub>A</sub>	PACKAG	E <sup>(2)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING <sup>(3)</sup>
–40°C to 125°C	SOT (SOT-23) - DBV	Reel of 3000	SN74LVC1G97QDBVRQ1	C97_
-40 C to 125 C	SOT (SC-70) - DCK	Reel of 3000	SN74LVC1G97QDCKRQ1	CS_

<sup>(1)</sup> For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

<sup>(2)</sup> Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

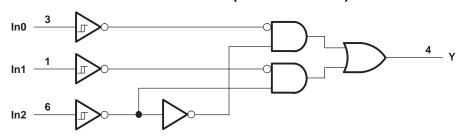
<sup>(3)</sup> DBV/DCK: The actual top-side marking has one additional character that designates the wafer fab/assembly site.



### **FUNCTION TABLE**

	INPUTS	OUTPUT	
ln2	ln1	In0	Y
L	L	L	∟
L	L	Н	L
L	Н	L	Н
L	Н	Н	Н
Н	L	L	L
Н	L	Н	Н
Н	Н	L	L
Н	Н	Н	Н

# LOGIC DIAGRAM (POSITIVE LOGIC)



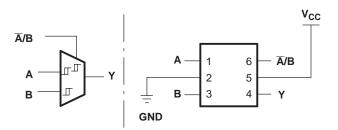
# **FUNCTION TABLE**

LOGIC FUNCTION	FIGURE NO.
2-to-1 data selector	1
2-input AND gate	2
2-input OR gate with one inverted input	3
2-input NAND gate with one inverted input	3
2-input AND gate with one inverted input	4
2-input NOR gate with one inverted input	4
2-input OR gate	5
Inverter	6
Noninverted buffer	7

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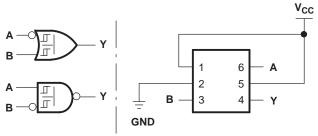
# LOGIC CONFIGURATIONS



 $V_{CC}$ 6 2 5 3 **GND** 

Figure 1. 2-to-1 Data Selector

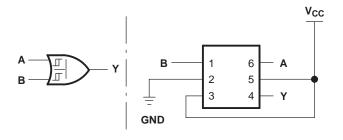
Figure 2. 2-Input AND Gate



 $\nu_{\text{cc}}$ П 6 В 2 5 4 GND

Figure 3. 2-Input OR Gate With One Inverted Input 2-Input NAND Gate With One Inverted Input

Figure 4. 2-Input AND Gate With One Inverted Input 2-Input NOR Gate With One Inverted Input



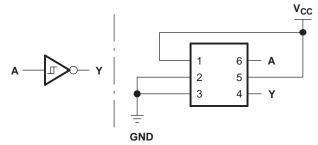


Figure 5. 2-Input OR Gate

Figure 6. Inverter

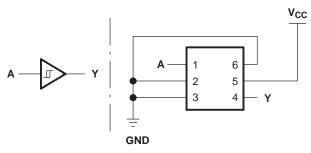


Figure 7. Noninverted Buffer



# Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	6.5	V
$V_{I}$	Input voltage range <sup>(2)</sup>	-0.5	6.5	V	
Vo	Voltage range applied to any output in the high-impedance	e or power-off state <sup>(2)</sup>	-0.5	6.5	V
Vo	Voltage range applied to any output in the high or low state	te <sup>(2)(3)</sup>	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		<b>-</b> 50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		<b>-</b> 50	mA
Io	Continuous output current			±50	mA
	Continuous current through V <sub>CC</sub> or GND			±100	mA
0	Package thermal impedance <sup>(4)</sup>	DBV package		165	°C/W
$\theta_{JA}$	гаскаде шеппанпречансе <sup>чу</sup>	DCK package		259	C/VV
T <sub>stg</sub>	Storage temperature range		-65	150	°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# Recommended Operating Conditions<sup>(1)</sup>

			MIN	MAX	UNIT
W	Complexed	Operating	1.65	5.5	\ /
V <sub>CC</sub>	Supply voltage	Data retention only	1.5		V
VI	Input voltage	·	0	5.5	V
Vo	Output voltage		0	$V_{CC}$	V
		V <sub>CC</sub> = 1.65 V		-4	
	OH High-level output current	V <sub>CC</sub> = 2.3 V		-8	
$I_{OH}$		V 2V		-16	mA
		$V_{CC} = 3 \text{ V}$		-24	
		V <sub>CC</sub> = 4.5 V		-24	
		V <sub>CC</sub> = 1.65 V		4	
		V <sub>CC</sub> = 2.3 V		8	
$I_{OL}$	Low-level output current	V 2V		16	mA
		V <sub>CC</sub> = 3 V		24	
		V <sub>CC</sub> = 4.5 V		24	
T <sub>A</sub>	Operating free-air temperature	·	-40	125	°C

All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed. The value of V<sub>CC</sub> is provided in the recommended operating conditions table.

The package thermal impedance is calculated in accordance with JESD 51-7.



### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

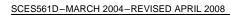
PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP <sup>(1)</sup> MAX	UNIT
		1.65 V	0.6	1.4	
_ V <sub>T+</sub>		2.3 V	1	1.8	
Positive-going input threshold		3 V	1.3	2.2	V
voltage		4.5 V	1.9	3.1	
		5.5 V	2.2	3.6	
		1.65 V	0.3	0.7	
$V_{T-}$		2.3 V	0.5	1	
Negative-going input threshold		3 V	0.7	1.4	V
voltage		4.5 V	1	2	
		5.5 V	1.2	2.3	
		1.65 V	0.3	0.8	
$\Delta V_{T}$		2.3 V	0.4	0.9	
Hysteresis		3 V	0.5	1	V
$(V_{T+} - V_{T-})$		4.5 V	0.6	1.5	
		5.5 V	0.7	1.7	
	$I_{OH} = -100 \mu\text{A}$	1.65 V to 5.5 V	V <sub>CC</sub> - 0.2		
	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2		
	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9		V
V <sub>OH</sub>	I <sub>OH</sub> = -16 mA	3 V	2.4		V
	J. 24 m A	3 V	2.3		
	$I_{OH} = -24 \text{ mA}$	4.5 V	3.8		
	I <sub>OL</sub> = 100 μA	1.65 V to 5.5 V		0.1	
	I <sub>OL</sub> = 4 mA	1.65 V		0.45	
	I <sub>OL</sub> = 8 mA	2.3 V		0.3	V
V <sub>OL</sub>	I <sub>OL</sub> = 16 mA	3 V		0.45	V
		3 V		0.55	
	I <sub>OL</sub> = 24 mA	4.5 V		0.58	
I <sub>I</sub>	V <sub>I</sub> = 5.5 V or GND	0 to 5.5 V		±5	μΑ
I <sub>off</sub>	$V_I$ or $V_O = 5.5 \text{ V}$	0		±10	μΑ
I <sub>CC</sub>	$V_1 = 5.5 \text{ V or GND}, \qquad I_0 = 0$	1.65 V to 5.5 V		10	μΑ
ΔI <sub>CC</sub>	One input at $V_{CC} - 0.6 \text{ V}$ , Other inputs at $V_{CC}$ or GND	3 V to 5.5 V		500	μΑ
C <sub>i</sub>	$V_I = V_{CC}$ or GND	3.3 V		3.5	pF

<sup>(1)</sup> All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25C.

# **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 8)

PARAMETER	PARAMETER FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 5 V ± 0.5 V		UNIT
		(001701)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	Any In	Υ	3.2	16.4	2	9.3	1.5	7.3	1.1	6.1	ns





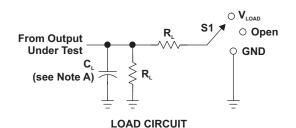
# **Operating Characteristics**

 $T_A = 25^{\circ}C$ 

PARAMETER		TEST	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V	V <sub>CC</sub> = 3.3 V	$V_{CC} = 5 V$	UNIT
		CONDITIONS	TYP	TYP	TYP	TYP	ONIT
$C_{pd}$	Power dissipation capacitance	f = 10 MHz	22	23	23	26	pF

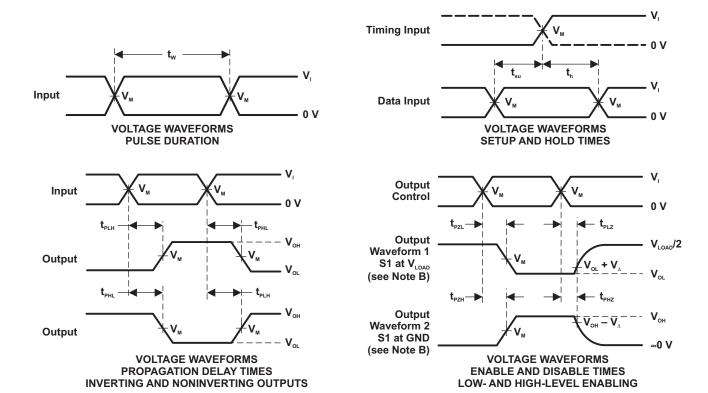


#### PARAMETER MEASUREMENT INFORMATION



TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	<b>V</b> <sub>LOAD</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

.,	IN	PUTS	.,	v		-	.,
V <sub>cc</sub>	V,	t,/t,	V <sub>M</sub>	V <sub>LOAD</sub>	C <sub>L</sub>	$R_{\scriptscriptstyle L}$	V <sub>A</sub>
1.8 V ± 0.15 V	V <sub>cc</sub>	≤2 ns	V <sub>cc</sub> /2	2 × V <sub>cc</sub>	30 pF	<b>1 k</b> Ω	0.15 V
2.5 V ± 0.2 V	$V_{cc}$	≤2 ns	V <sub>cc</sub> /2	2 × V <sub>cc</sub>	30 pF	<b>500</b> Ω	0.15 V
3.3 V ± 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	50 pF	<b>500</b> Ω	0.3 V
5 V ± 0.5 V	$V_{cc}$	≤2.5 ns	V <sub>cc</sub> /2	2 × V <sub>cc</sub>	50 pF	500 Ω	0.3 V



NOTES: A. C, includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_{o}$  = 50  $\Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $\dot{t}_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{\mbox{\tiny PLH}}$  and  $t_{\mbox{\tiny PHL}}$  are the same as  $t_{\mbox{\tiny pd}}.$
- H. All parameters and waveforms are not applicable to all devices.

Figure 8. Load Circuit and Voltage Waveforms



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#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC1G97QDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C97O	Samples
SN74LVC1G97QDCKRQ1	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	(CSJ, CSO)	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF SN74LVC1G97-Q1:

Catalog: SN74LVC1G97

● Enhanced Product : SN74LVC1G97-EP

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

• Enhanced Product - Supports Defense, Aerospace and Medical Applications



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# TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G97QDBVRQ1	SOT-23	DBV	6	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
SN74LVC1G97QDCKRQ1	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3





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### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G97QDBVRQ1	SOT-23	DBV	6	3000	180.0	180.0	18.0
SN74LVC1G97QDCKRQ1	SC70	DCK	6	3000	180.0	180.0	18.0

# DCK (R-PDSO-G6)

# PLASTIC SMALL-OUTLINE PACKAGE



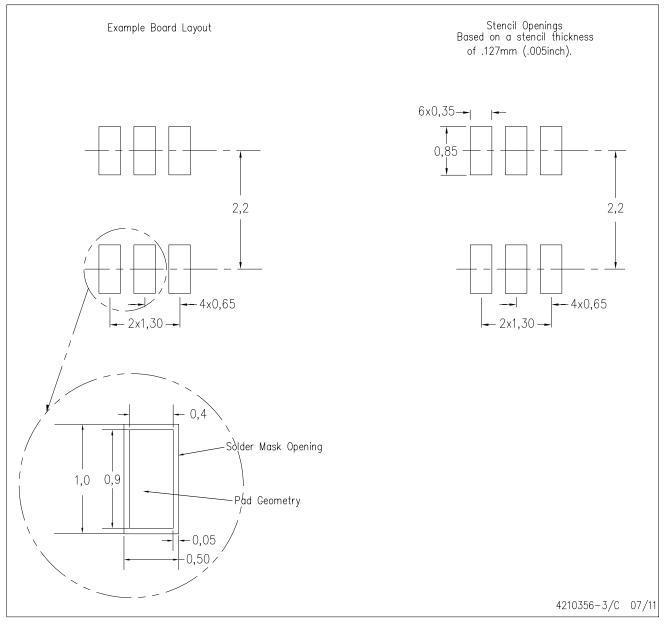
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AB.



# DCK (R-PDSO-G6)

# PLASTIC SMALL OUTLINE



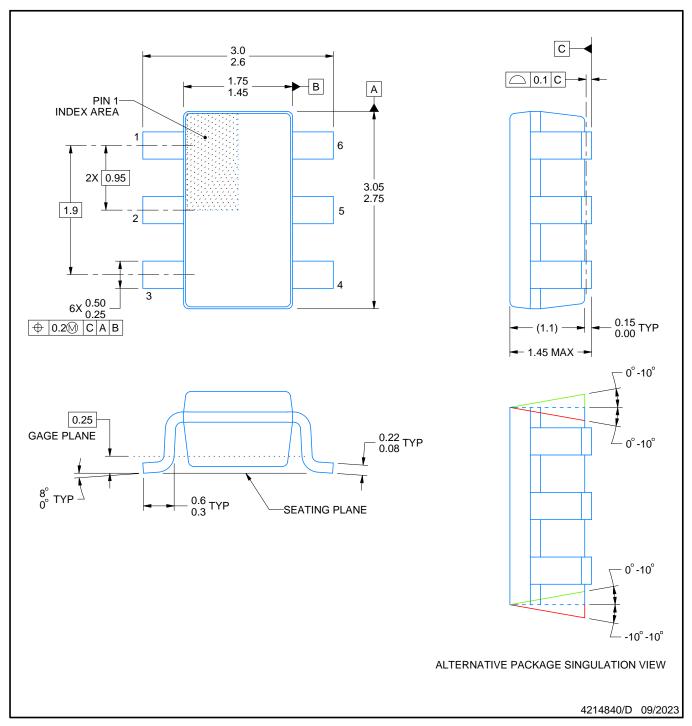
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.





SMALL OUTLINE TRANSISTOR



### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

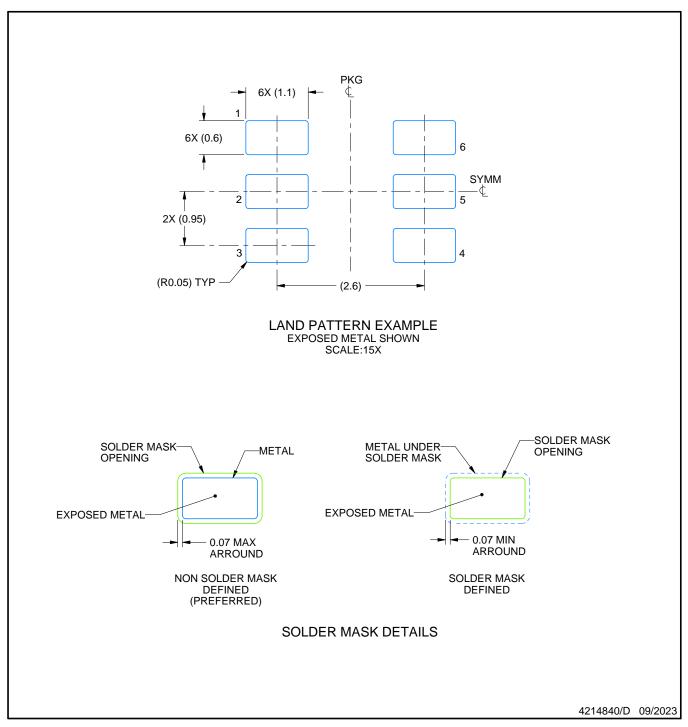
  2. This drawing is subject to change without notice.

  3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.

- 4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- 5. Refernce JEDEC MO-178.



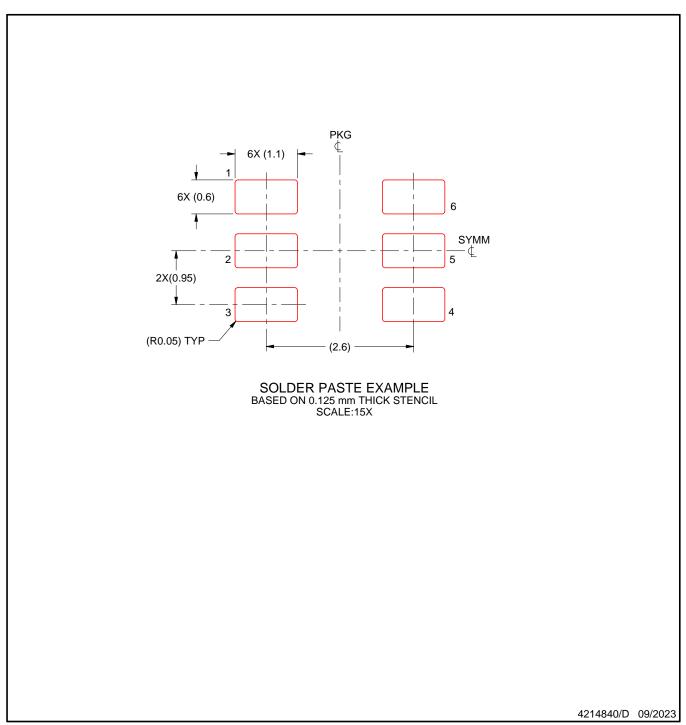
SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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